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SHEET 1 OF 1 INFORMATION DISCLOSURE ATTY. DOCKET NO. SERIAL NO Not Yet Assigned 071971-0643 CITATION IN AN APPLICATION APPLICANT Shunsaku MURAOKA, et al. FILING DATE GROUP (PTO-1449) June 26, 2006 Not Yet Assigned U.S. PATENT DOCUMENTS EXAMINER'S Document Number Publication Date Name of Patentee or Applicant of Cited Pages, Columns, Lines, Where INITIALS MM-DD-YYYY Number-Kind Codes or answer Document Relevant Passages or Relevant Figures Appear US 2003/038301 A1 02/27/2003 Moore US 6.583,003 B1 06/24/2003 Hsu, et al. US 6.344.991 B1 02/05/2002 Mikami et al. US 5.969.990 A 10/19/1999 Arase et al. 6,226,197 B1 05/01/2001 US Nishimura HS 6.473.332 B1 10/29/2002 Charlson, et al US 6.574.138 B2 06/03/2003 Schwarzl et al. US 6,278,138 B1 08/21/2001 Suzuki FOREIGN PATENT DOCUMENTS EXAMINER'S Foreign Patent Document Publication Date Name of Patentee or Translation Pages, Columns, Lines Applicant of Cited Document INITIAL S CITE Country Codes -Number +-Kind MM-DD-YYYY Where Relevant Yes No Codes (if known) Figures Appear NO WO 02/19337 A 03/07/2002 MOTOROLA, INC. EP 1 426 966 A 06/09/2004 SHARP KK EP 1 455 363 A 09/08/2004 SHARP KABUSHIKI KAISHA OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.) Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published. EYAMINED'S INITIALS CITE Zhuang W., et al. "Novel colossal magnetoresistive thin film nonvolatile resistance random access memory (RRAM)" Technical Digest of International Electron Devices Meeting 2002. San Francisco, CA, December 8-11; New York, NY December 8, pp. 193-196. EXAMINER DATE CONSIDERED /Nam Nguyen/ (07/24/2008)

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